

2SB0948, 2SB0948A (2SB948, 2SB948A)

Silicon PNP epitaxial planar type

For low-voltage switching

Complementary to 2SD1445 and 2SD1445A

■ Features

- Low collector to emitter saturation voltage $V_{CE(sat)}$
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Collector to base voltage	2SB0948	V_{CBO}	−40	V
	2SB0948A		−50	
Collector to emitter voltage	2SB0948	V_{CEO}	−20	V
	2SB0948A		−40	
Emitter to base voltage		V_{EBO}	−5	V
Peak collector current		I_{CP}	−20	A
Collector current		I_C	−10	A
Collector power dissipation	$T_C = 25^{\circ}\text{C}$	P_C	40	W
	$T_a = 25^{\circ}\text{C}$		2	
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature		T_{stg}	−55 to +150	$^{\circ}\text{C}$

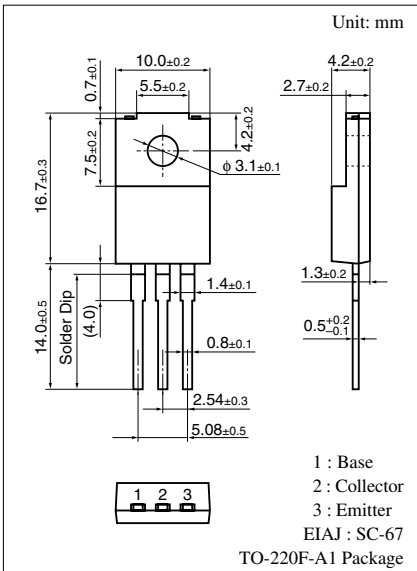
■ Electrical Characteristics $T_C = 25^\circ\text{C}$

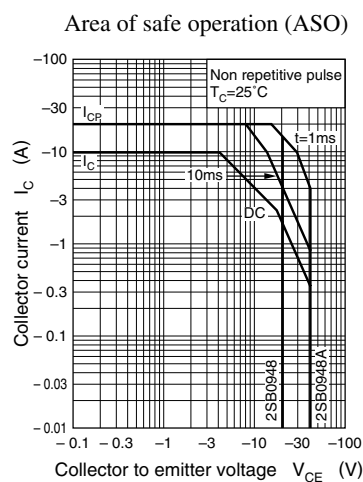
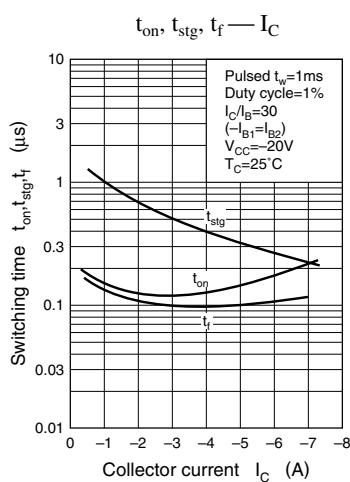
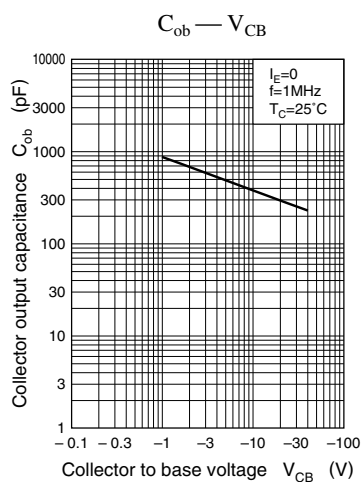
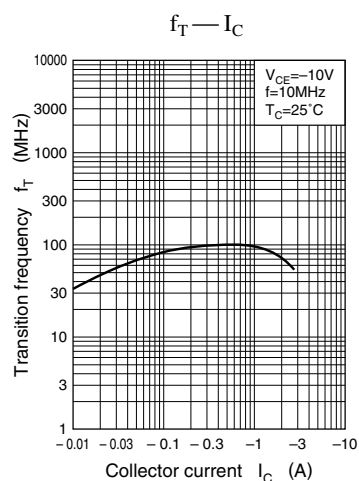
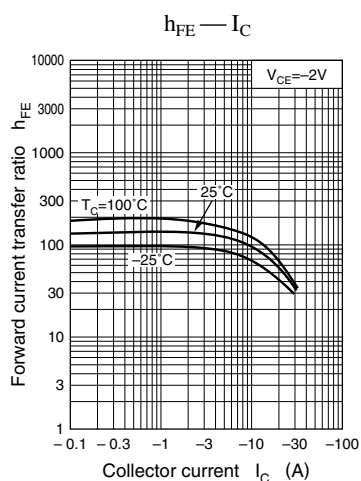
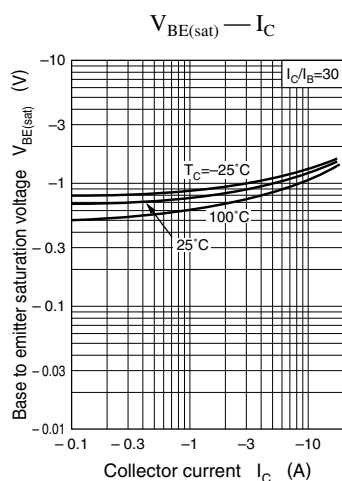
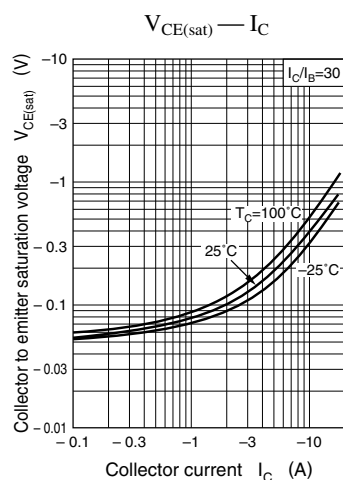
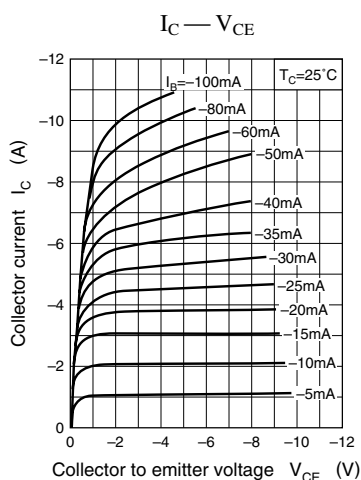
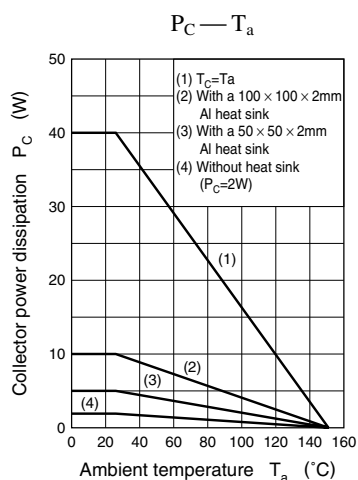
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -40\text{ V}, I_E = 0$			-50	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$			-50	μA
Collector to emitter voltage	2SB0948 2SB0948A	V_{CEO}	$I_C = -10\text{ mA}, I_B = 0$	-20		V
				-40		
Forward current transfer ratio	h_{FE1}	$V_{CE} = -2\text{ V}, I_C = -0.1\text{ A}$	45			
	h_{FE2}^*	$V_{CE} = -2\text{ V}, I_C = -3\text{ A}$	90		260	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10\text{ A}, I_B = -0.33\text{ A}$			-0.6	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = -10\text{ A}, I_B = -0.33\text{ A}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -10\text{ V}, I_C = -0.5\text{ A}, f = 10\text{ MHz}$		100		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$		400		pF
Turn-on time	t_{on}	$I_C = -3\text{ A}, I_{B1} = -0.1\text{ A}, I_{B2} = 0.1\text{ A}$		0.1		μs
Storage time	t_{stg}			0.5		μs
Fall time	t_f			0.1		μs

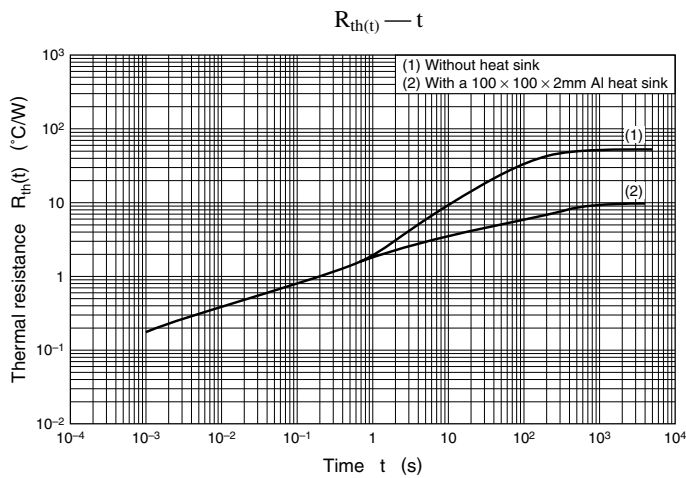
Note) *: Rank classification

Rank	Q	P
h_{FE2}	90 to 180	130 to 260

Note.) The Part numbers in the Parenthesis show conventional part number.







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